

SAMTM Data Sheet SAM-1040-50-1ps-x, λ = 1040nm

Laser wavelength $\lambda = 1040 \text{ nm}$

High reflection band $\lambda = 980 ... 1060 \text{ nm}$

 $\begin{array}{ll} \mbox{Absorbance} & \mbox{$A_0=50$ \%} \\ \mbox{Modulation depth} & \mbox{$\Delta R=30$ \%} \\ \mbox{Non-saturable loss} & \mbox{$A_{\rm ns}=20$ \%} \end{array}$

Saturation fluence $\Phi_{\text{sat}} = 70 \,\mu\text{J/cm}^2$

Relaxation time constant $\tau = 1 \text{ ps}$

Damage threshold $\Phi = 800 \,\mu\text{J/cm}^2$

Chip area 4.0 mm x 4.0 mm; other dimensions on request

Chip thickness 450 µm

Protection the SAM is protected with a dielectric front layer

Mounting option **x** denotes the type of mounting as follows:

x = 0
x = 12.7 g
x = 25.4 g
x = 12.7 s
x = 25.4 s
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Low intensity spectral reflectance

